imall

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High Voltage LED Series Chip on Board

LCo40D-Gen.2



High efficacy COB LED package well-suited for use in spotlight applications

Features & Benefits

- Chip on Board (COB) solution makes it easy to design in
- Simple assembly reduces manufacturing cost
- Low thermal resistance
- InGaN/GaN MQW LED with long time reliability

Applications

- Spotlight / Downlight
- LED Retrofit Bulbs
- Outdoor Illumination







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1. Characteristics

a) Absolute Maximum Rating

ltem	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	Ta	-40 ~ +105	δ	-
Storage Temperature	T _{stg}	-40 ~ +120	۶C	-
LED Junction Temperature	Tj	150	۶C	-
Case Temperature	Тс	115	°C	
Forward Current	lF	2760	mA	-
Power Dissipation	PD	103.5	W	-
ESD (HBM)	-	<u>+2</u>	kV	-
ESD (MM)	-	±0.5	kV	-

b) Electro-optical Characteristics (IF = 1080 mA, TJ = 85 $^{\circ}$ C)

Item	Unit	Rank	Min.	Тур.	Max.
Forward Voltage (VF)	V	YZ	31.8	34.6	37.5
		3	70	-	-
Color Rendering Index (Ra)	-	5	80	-	-
		7	90		
Thermal Resistance (junction to case point)	°C/W		-	0.32	-
Beam Angle	Q		-	115	-
Nominal Power	W			37.4	

Notes:

1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ($T_J = T_C = T_a = 85 \text{ °C}$)

2) Samsung maintains measurement tolerance of: forward voltage = ± 5 %, CRI = ± 1

3) Refer to the derating curve, '3. Typical Characteristics Graph' designed within the range.

c) Luminous Flux Characteristics $(I_F = 1080 \text{ mA})$

CRI (R _a)	Nominal	Flux	Flux @ T₅ = 85 °C (Im)			
Min.	CCT (K)	Rank	Min.	Тур.	Max.	
	3000	D2	5989	6304		
70	4000	D2	6180	6506		
	5000	D2	6276	6607		
	2700	D2	5270	5547	-	
	3000	D2	5545	5837	-	
	3500	D2	5715	6016	-	
80	4000	D2	5838	6146	-	
	5000	D2	5866	6175	-	
	5700	D2	5894	6205	-	
	6500	D2	5831	6138	-	
	2700	D2	4517	4755	-	
	3000	D2	4773	5024	-	
90	3500	D2	4894	5152	-	
	4000	D2	5002	5266	-	
	5000	D2	5059	5325	-	

Notes:

- 1) The COB is tested in pulsed operating condition at rated test current (10 ms pulse width) and rated temperature $(T_J = T_C = 85 \text{ °C}).$
- 2) Samsung maintains measurement tolerance of: Luminous flux = ± 7 %, CRI = ± 1

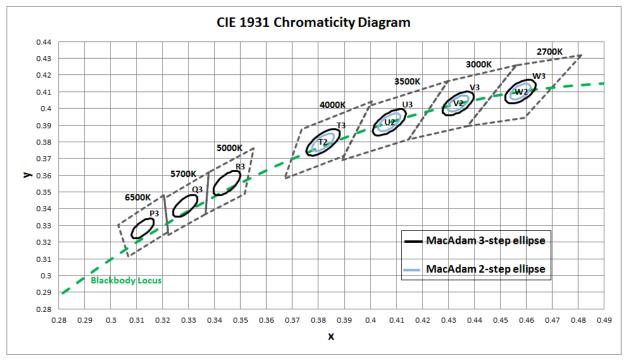
2. Product Code Information

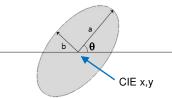
1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	Р	н	W	н	Α	н	D	Ν	К	2	5	Y	Z	W	3	D	2

Digit	PKG Information	Code	Specification
1 2 3	Samsung Package High Power	SPH	
4 5	Color	WH	White
6	Product Version	Α	
78	Form Factor	HD	СОВ
9	Lens Type	N	No lens
10	Wattage or Model	к	LC040D
11	Internal Code	2	
		3	Min. 70 (85°C)
12	CRI & Sorting Temperature	5	Min. 80 (85°C)
		7	Min. 90 (85°C)
13 14	Forward Voltage (V)	YZ	31.8 ~ 37.5
		w	2700К
		v	3000K
		U	3500K
15	CCT (K)	т	4000K
		R	5000K
		Q	5700K
		Р	6500K
16	MacAdam Step	2	MacAdam 2-step
		3	MacAdam 3-step
17 18	Luminous Flux	D2	COB D-series Gen.2 level

a) Binning Structure $(I_F = 1080 \text{ mA}, T_J = 85 \text{ }^{\circ}\text{C})$

CRI (R₀) Min.	Nominal CCT (K)	Product Code	V _F Rank	Color Rank	Flux Rank	Flux Range (Φ _v , lm)
	3000	SPHWHAHDNK23YZV3D2	ΥZ	V3	D2	5989 ~
70	4000	SPHWHAHDNK23YZT3D2	YZ	Т3	D2	6180 ~
	5000	SPHWHAHDNK23YZR3D2	YZ	R3	D2	6276 ~
		SPHWHAHDNK25YZW2D2		W2		
	2700	SPHWHAHDNK25YZW3D2	YZ	W3	D2	5270 ~
		SPHWHAHDNK25YZV2D2		V2	5.0	
	3000	SPHWHAHDNK25YZV3D2	YZ	V3	D2	5545 ~
		SPHWHAHDNK25YZU2D2		U2		
80	3500	SPHWHAHDNK25YZU3D2	YZ	U3	D2	5715 ~
		SPHWHAHDNK25YZT2D2		Τ2		
	4000	SPHWHAHDNK25YZT3D2	YZ	Т3	D2	5838 ~
	5000	SPHWHAHDNK25YZR3D2	YZ	R3	D2	5866 ~
	5700	SPHWHAHDNK25YZQ3D2	YZ	Q3	D2	5894 ~
	6500	SPHWHAHDNK25YZP3D2	ΥZ	P3	D2	5831 ~
	0700	SPHWHAHDNK27YZW2D2	\/7	W2	50	4647
	2700	SPHWHAHDNK27YZW3D2	YZ	W3	D2	4517 ~
		SPHWHAHDNK27YZV2D2		V2		
	3000	SPHWHAHDNK27YZV3D2	YZ	V3	D2	4773 ~
90		SPHWHAHDNK27YZU2D2		U2	5.0	
	3500	SPHWHAHDNK27YZU3D2	YZ	U3	D2	4894 ~
		SPHWHAHDNK27YZT2D2		Τ2	8-	
	4000	SPHWHAHDNK27YZT3D2	YZ	Т3	D2	5002 ~
	5000	SPHWHAHDNK27YZT2D2	ΥZ	T2	D2	5059 ~





MacAdam Ellipse (W2, W3)									
Step CIE x CIE y θ a b									
2-step	0.4578	0.4101	53.70	0.0054	0.0028				
3-step	0.4578	0.4101	53.70	0.0081	0.0042				

MacAdam Ellipse (U2, U3)									
Step	CIE x	CIE y			b				
2-step	0.4073	0.3917	54.00	0.0062	0.0028				
3-step	0.4073	0.3917	54.00	0.0093	0.0041				

MacAdam Ellipse (R3)									
Step CIE x CIE y θ a b									
3-step	0.3447	0.3553	59.62	0.0082	0.0035				

MacAdam Ellipse (P3)									
Step	CIE x	CIE y			b				
3-step	0.3123	0.3282	58.5700	0.0067	0.0029				

MacAdam Ellipse (V2, V3)									
Step CIE x CIE y θ a b									
2-step	0.4338	0.403	53.22	0.0056	0.0027				
3-step	0.4338	0.4030	53.22	0.0083	0.0041				

MacAdam Ellipse (T2, T3)						
Step	CIE x	CIE y			b	
2-step	0.3818	0.3797	53.72	0.0063	0.0027	
3-step	0.3818	0.3797	53.72	0.0094	0.0040	

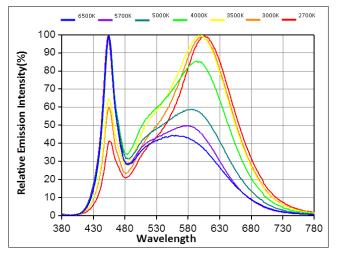
MacAdam Ellipse (Q3)						
Step	CIE x	CIE y			b	
3-step	0.3287	0.3417	59.0950	0.0075	0.0032	

Note:

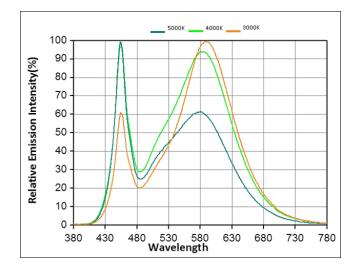
Samsung maintains measurement tolerance of: Cx, Cy = ± 0.005

3. Typical Characteristics Graphs

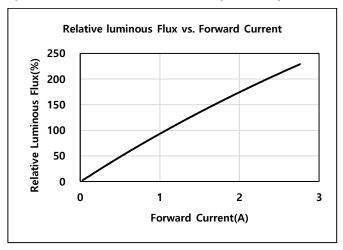
a) Spectrum Distribution (IF = 1080 mA, TJ = 85 $^{\circ}$ C) CRI Ra 80+

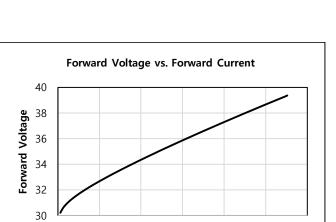


CRI Ra 70+



b) Forward Current Characteristics (T_J = 85 °C)





1.5

Forward Current(A)

1

2

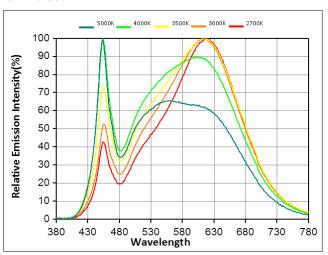
2.5

3

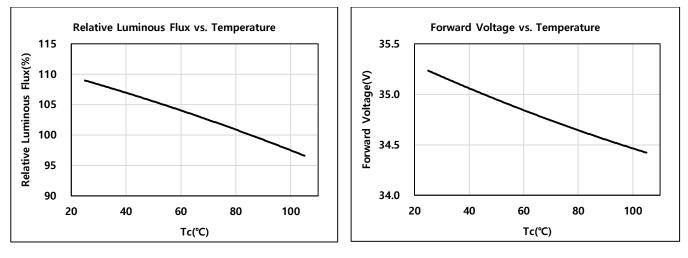
0

0.5

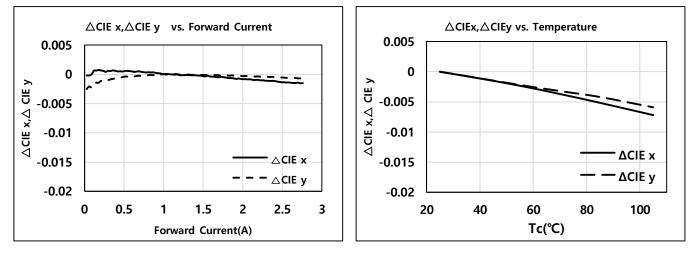
CRI Ra 90+



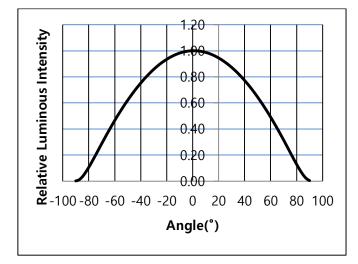
c) Temperature Characteristics (I_F = 1080mA)

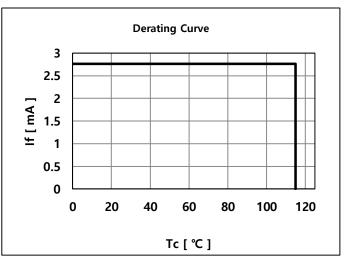


d) Color Shift Characteristics ($T_J = 85 \ ^{\circ}C$, $I_F = 1080$ mA, CRI = 80+)

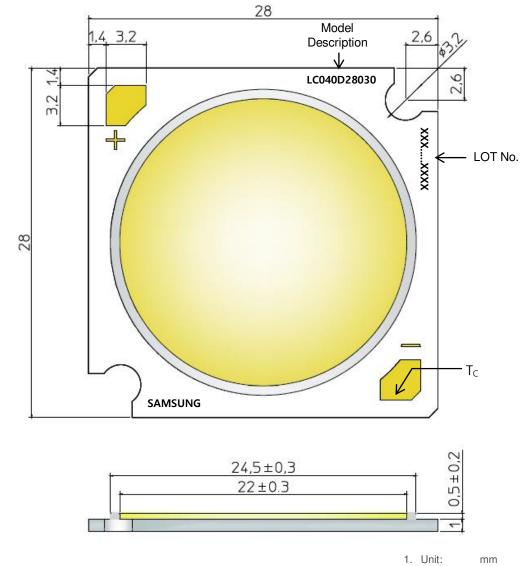


e) Beam Angle Characteristics (I_F = 1080 mA, T_J = 85 °C) f) Derating Characteristics





4. Outline Drawing & Dimension



^{2.} Tolerance: ± 0.3 mm

Item	Dimension	Tolerance	Unit
Length	28.0	±0.15	mm
Width	28.0	±0.15	mm
Height	1.50	±0.20	mm
Light Emitting Surface (LES) Diameter	22.0	±0.30	mm

Note: Denoted product information above is only an example (LC040D28030 : LC040D, Gen2, CRI80+, 3000K)

5. Reliability Test Items & Conditions

a) Test Items

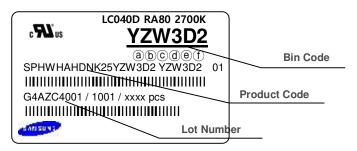
Test Item	Test Condition	Test Hour / Cycle
High Temperature Humidity Life Test	60 ºC, 90 % RH,, DC Derating, I⊧	1000 h
High Temperature Life Test	85 ºC, DC Derating, I⊧	1000 h
Low Temperature Life Test	-40 °C, DC, Derating I⊧	1000 h
High Temperature Storage	120 ºC	1000 h
Low Temperature Storage	-40 °C	1000 h
Temperature Humidity Storage	60 °C, 90% RH	1000h
Temperature Cycle On/Off Test	-40 $^{\rm e}C$ / 85 $^{\rm e}C$ each 20 min, 30 min transfer power on/off each 5 min, DC Derating, $I_{\rm F}$ = max	100 cycles
ESD (HBM)	R ₁ : 10 MΩ R ₂ : 1.5 kΩ C: 100 pF	5 times
ESD (MM)	R ₁ : 10 MΩ R ₂ : 0 kΩ C: 200 pF	5 times
Vibration Test	20 ~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency ↔ max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times
Sulfur Resistance	25 °C, 75%, H2S 15 ppm	504h

b) Criteria for Judging the Damage

ltem	Symbol	Test Condition L		nit
	Symbol	(T _c = 25 °C)	Min.	Max.
Forward Voltage	VF	I _F = 1080 mA	L.S.L. * 0.9	U.S.L. * 1.1
Luminous Flux	Φν	I⊧ = 1080 mA	L.S.L * 0.7	U.S.L * 1.3

6. Label Structure

a) Label Structure



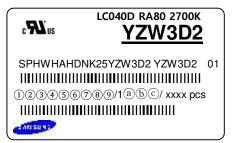
Note: Denoted bin code and product code above is only an example (see description on page 5)

Bin Code:

- (a) (b): Forward Voltage bin (refer to page 11)
- ©d: Chromaticity bin (refer to page 9-10)
- (e) f): Luminous Flux bin (refer to page 6)

b) Lot Number

The lot number is composed of the following characters:

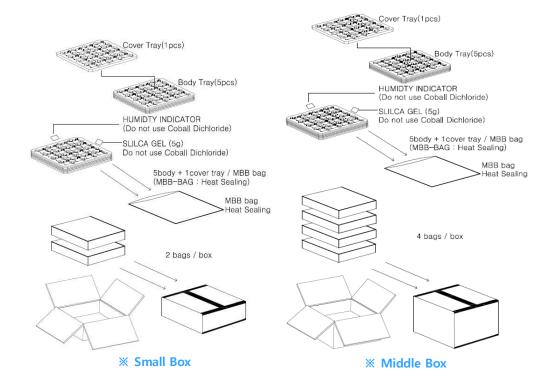


- 1 3456789 / 1abc / xxxx pcs
- 1 : Production site (S: Giheung, Korea, G: Tianjin, China)
- 2 : 4 (LED)
- ③ : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)
- (4) : Year (Z: 2015, A: 2016, B: 2017...)
- (5) : Month (1~9, A, B, C)
- 6789 : Day (1~9, A, B~V)
- (a)b)c) : Product serial number (001 ~ 999)

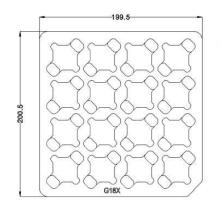
7. Packing Structure

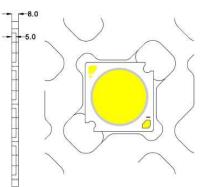
	Max. quantity	Dimension(mm)			
Packing material	in pcs of COB	Length	Width	Height	Tolerance
Тгау	16	200	200	8	1
Anti-Static Bag	80 (5 trays)	320	270	-	+/- 0.5
Outer Box (Small)	160 (2 bags)	225	225	65	5
Outer Box (Middle)	320 (4 bags)	225	225	130	5

a) Packing Structure



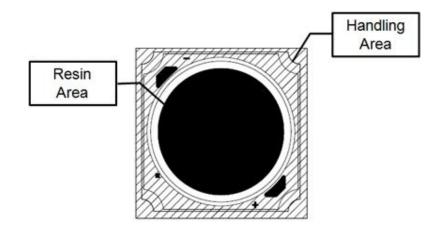
b) Tray





8. Precautions in Handling & Use

- This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
 a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
 b. Stored at <10 % RH
- 4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 5) Devices require baking before mounting, if humidity card reading is >60 % at 23 \pm 5 °C.
- 6) Devices must be baked for 1 hour at $60 \pm 5 \,^{\circ}$ C, if baking is required.
- 7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or antielectrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- The thermal management is one of the most critical factors for the LED lighting system. Especially the LED junction temperature should not exceed the absolute maximum rating while operation of LED lighting system.
 For more information, please refer to Application Note 'Mechanical & Thermal Guide for COB'.
- 9) In case of driving LEDs around the minimum current level (If_min), chips might exhibit different brightness due to the variation in I-V characteristics of each one. This is normal and does not adversely affect the performance of product.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 11) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.



Legal and additional information.

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